

1. General description

Planar passivated SCR with sensitive gate in a SIP3 (SOT82) plastic package intended for use in general purpose switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Sensitive gate
- · Planar passivated for voltage ruggedness and reliability
- · Direct triggering from low power drivers and logic ICs

3. Applications

- Adapters
- Battery powered applications
- Industrial automation

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 1</u>		-	-	2.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	4	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>		-	-	35	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms		-	-	38	A
Tj	junction temperature		[1]	-	-	125	°C
Static chara	acteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		-	15	200	μA
Dynamic ch	naracteristics				-	_	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12		-	50	-	V/µs

[1] Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	[]	
2	А	anode		
3	G	gate		
mb	A	mounting base; connected to anode		
			SIP3 (SOT82)	

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BT148-500R	SIP3	plastic single-ended package; 3 leads (in-line)	SOT82		

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		[1]	-	500	V
V _{RRM}	repetitive peak reverse voltage			-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 1</u>		-	2.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 113 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	4	A
	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; Fig. 4; Fig. 5		-	35	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms		-	38	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN		-	6.1	A²s
dl _T /dt	rate of rise of on-state current	I_T = 10 A; I_G = 50 mA; dI_G/dt = 50 mA/µs		-	50	A/µs
I _{GM}	peak gate current			-	2	А
V _{RGM}	peak reverse gate voltage			-	5	V
P _{GM}	peak gate power			-	5	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.5	W
T _{stg}	storage temperature			-40	150	°C
Tj	junction temperature		[2]	-	125	°C

[1] Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s. Operation above 110°C may require the use of a gate to cathode resistor of 1k Ω or less.

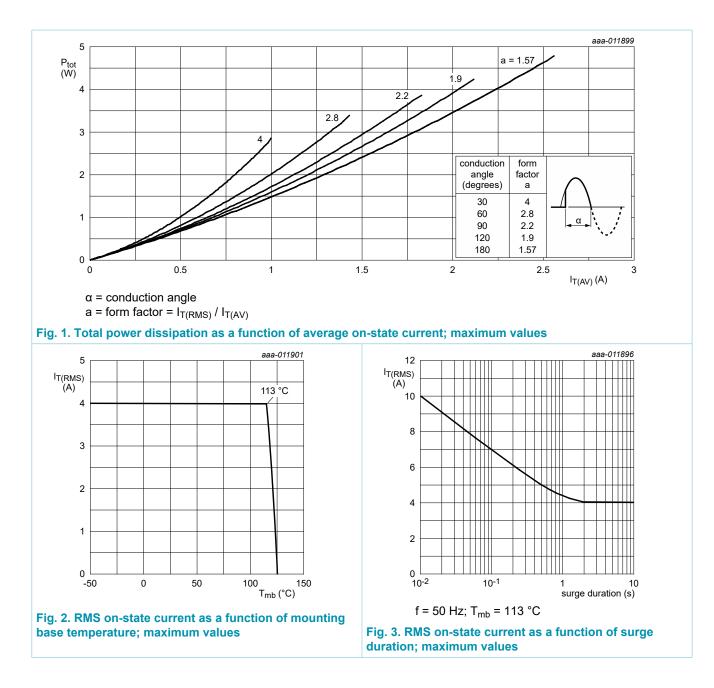
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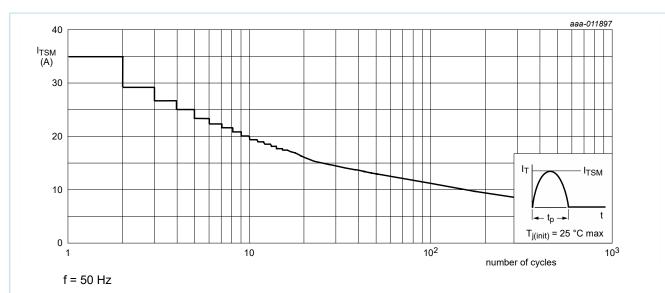


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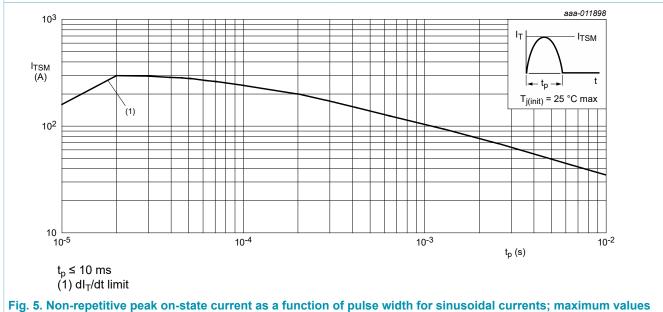
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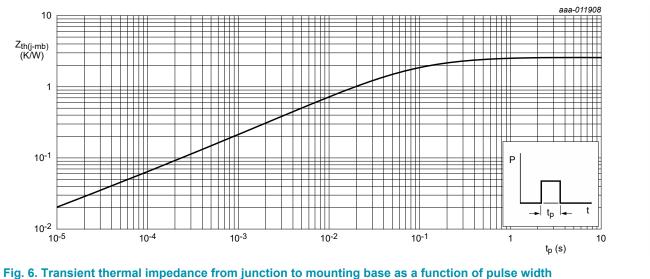






8. Thermal characteristics

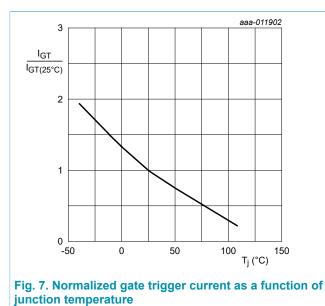
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	95	-	K/W

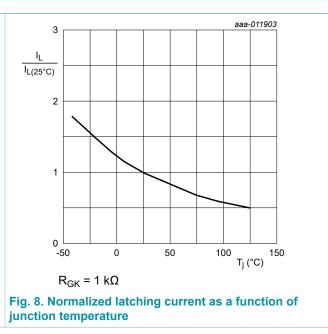


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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	15	200	μA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	0.17	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	0.1	6	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.23	1.8	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.4	1	V
		V_D = 500 V; I _T = 0.1 A; T _j = 110 °C; Fig. 11	0.1	0.2	-	V
ID	off-state current	V _D = 500 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 500 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 100 Ω; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	-	50	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 10 A; V _D = 500 V; I _G = 5 mA; dI _G / dt = 0.2 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 268 V; T _j = 125 °C; I _{TM} = 8 A; V_R = 10 V; (dI _T /dt) _M = 10 A/µs; dV _D / dt = 2 V/µs; R _{GK(ext)} = 1 kΩ; (V _{DM} = 67% of V _{DRM})	-	100	-	μs

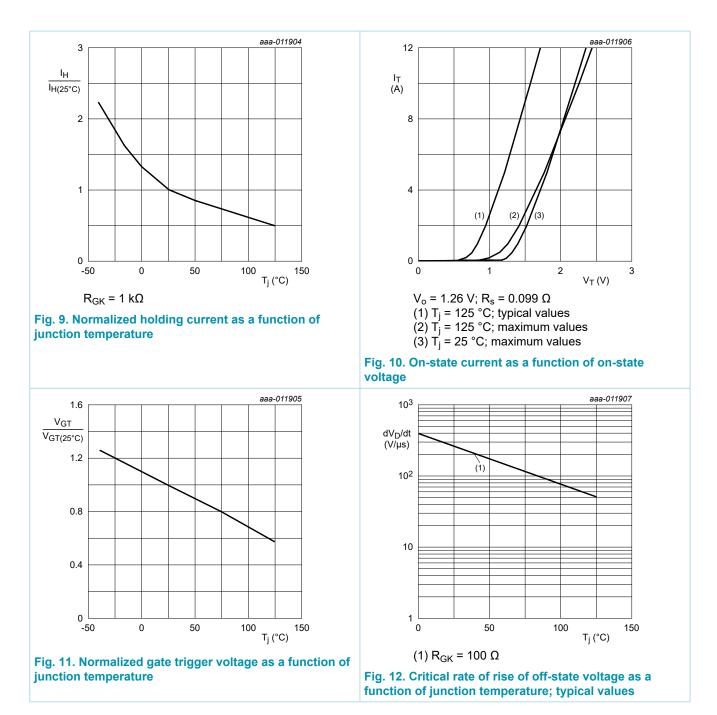




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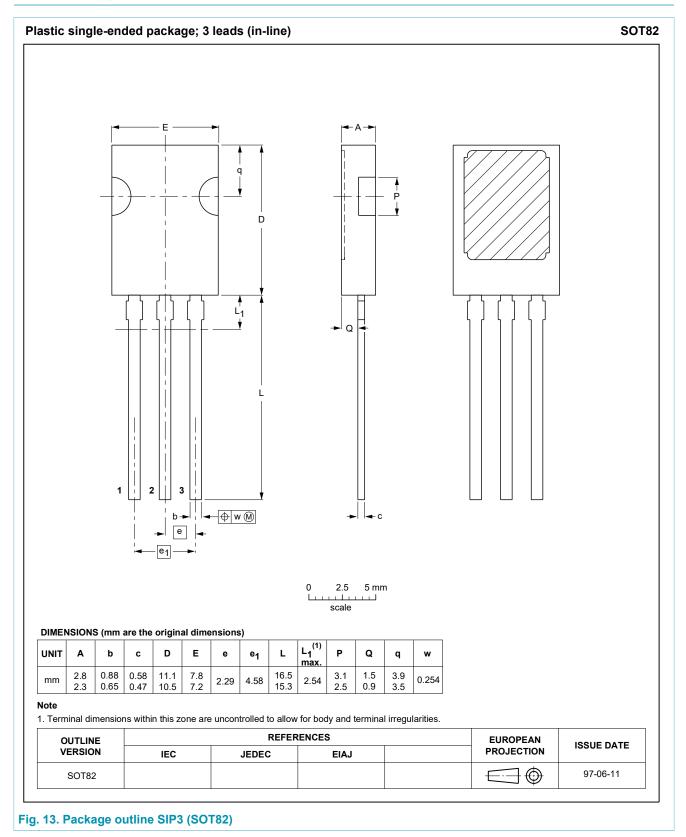
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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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